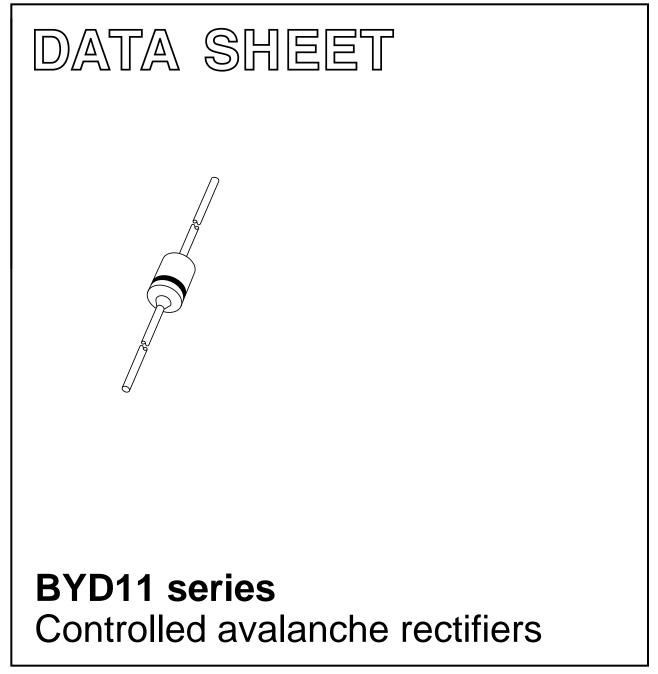
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of April 1992 File under Discrete Semiconductors, SC01 1996 May 24



FEATURES

- · Glass passivated
- High maximum operating temperature
- Low leakage current
- · Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack.

DESCRIPTION

Cavity free cylindrical glass package through Implotec^{TM(1)} technology.

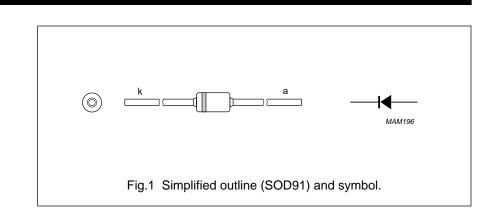
This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

(1) Implotec is a trademark of Philips.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage				
	BYD11D		_	200	V
	BYD11G		_	400	V
	BYD11J		_	600	V
	BYD11K		_	800	V
	BYD11M		_	1000	V
V _{RWM}	crest working reverse voltage				
	BYD11D		_	200	V
	BYD11G		_	400	V
	BYD11J		-	600	V
	BYD11K		_	800	V
	BYD11M		_	1000	V
V _R	continuous reverse voltage				
	BYD11D		_	200	V
	BYD11G		_	400	V
	BYD11J		_	600	V
	BYD11K		_	800	V
	BYD11M		—	1000	V



MARKING

TYPE NUMBER	MARKING CODE
BYD11D	11D
BYD11G	11G
BYD11J	11J
BYD11K	11K
BYD11M	11M

BYD11 series

BYD11 series

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{F(AV)}	average forward current	$T_{tp} = 55 \text{ °C};$ lead length = 10 mm; averaged over any 20 ms period; see Figs 2 and 4	_	0.50	A
		$T_{amb} = 60 \ ^{\circ}C$; PCB mounting (see Fig.9); averaged over any 20 ms period; see Figs 3 and 4	-	0.37	A
I _{FSM}	non-repetitive peak forward current	t = 10 ms half sinewave; $T_j = T_{j max}$ prior to surge; $V_R = V_{RRMmax}$	-	10	A
P _{RSM}	non-repetitive peak reverse power dissipation	t = 20 μ s half sinewave; T _j = T _{j max} prior to surge	-	200	W
T _{stg}	storage temperature		-65	+175	°C
Tj	junction temperature	see Fig.5	-65	+175	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	$I_{F} = 0.5 \text{ A}; T_{j} = T_{j \text{ max}}; \text{ see Fig.6}$	_	_	0.91	V
		I _F = 0.5 A; see Fig.6	_	_	1.06	V
V _{(BR)R}	reverse avalanche breakdown voltage	I _R = 0.1 mA				
	BYD11D		225	_	_	V
	BYD11G		450	_	_	V
	BYD11J		650	-	_	V
	BYD11K		900	_	-	V
	BYD11M		1100	-	_	V
I _R	reverse current	$V_R = V_{RRMmax}$; see Fig.7	-	-	1	μΑ
		$V_R = V_{RRMmax}$; $T_j = 165 \text{ °C}$; see Fig.7	-	-	75	μΑ
t _{rr}	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig.10	_	3	_	μs
C _d	diode capacitance	V _R = 0 V; f = 1 MHz; see Fig.8	-	14	-	pF

THERMAL CHARACTERISTICS

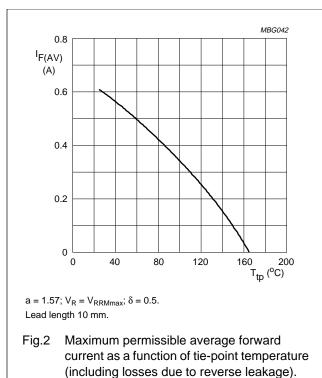
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length = 10 mm	180	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	250	K/W

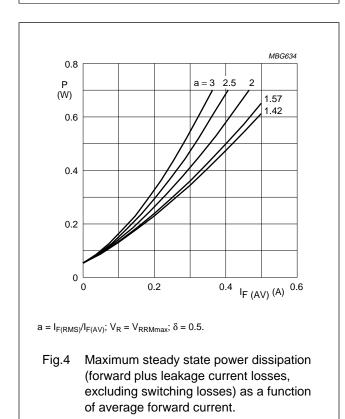
Note

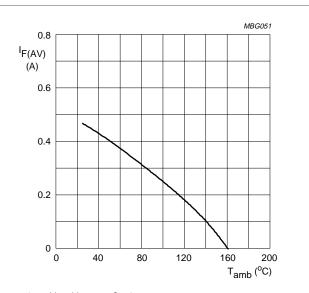
1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper ≥40 μm, see Fig.9. For more information please refer to the *"General Part of Handbook SC01"*.

BYD11 series

GRAPHICAL DATA

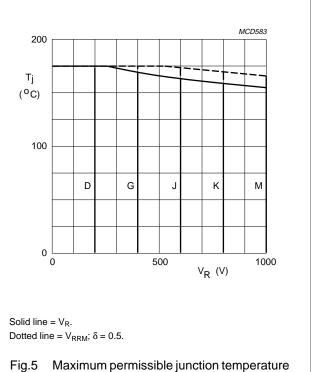




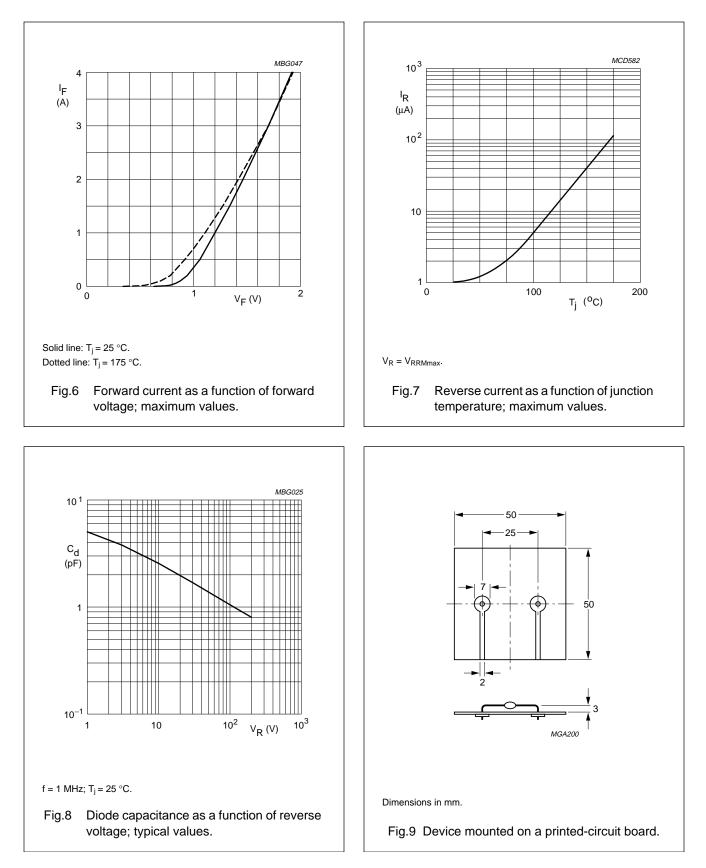


a = 1.57; $V_R = V_{RRMmax}$; $\delta = 0.5$. Device mounted as shown in Fig.9.

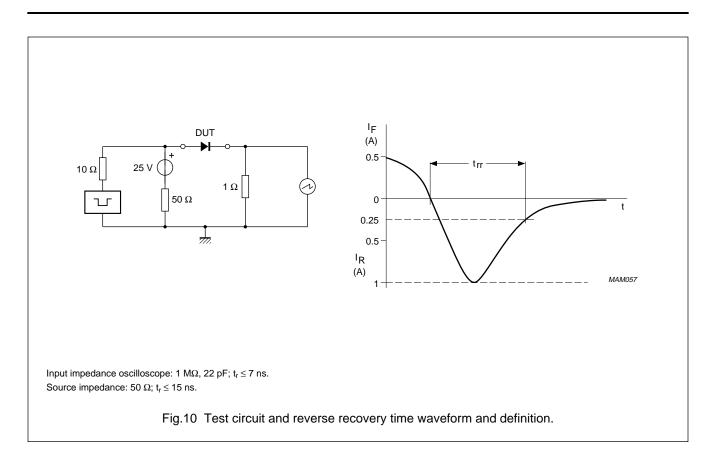
Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



BYD11 series

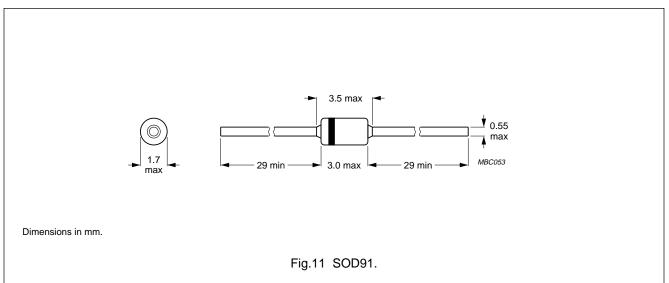


BYD11 series



BYD11 series

PACKAGE OUTLINE



DEFINITIONS

et or goal specifications for product development. minary data; supplementary data may be published later. product specifications.
product specifications.
Aximum Rating System (IEC 134). Stress above one or to the device. These are stress ratings only and operation be given in the Characteristics sections of the specification ods may affect device reliability.
bes not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.